



**TECH PUBLIC**

台舟电子

**SS32 THRU SS320**

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### Surface Mount Schottky Barrier Rectifier

Reverse Voltage - 20 to 200 V

Forward Current - 3.0A

#### Features

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

#### MECHANICAL DATA

- Case: SMA
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 60mg / 0.0021oz

#### PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Top View  
Marking Code: SS32~SS320  
Simplified outline SMA and symbol

#### Absolute Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

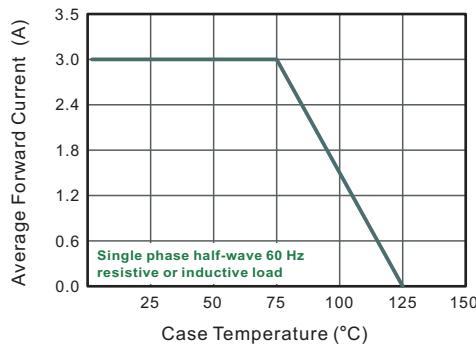
Parameter	Symbols	SS32	SS34	SS34A	SS36	SS38	SS310	SS312	SS315	SS320	Units						
Maximum Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	20	40	45	60	80	100	120	150	200	V						
Maximum RMS voltage	V <sub>RMS</sub>	14	28	31.5	42	56	70	84	105	140	V						
Maximum DC Blocking Voltage	V <sub>DC</sub>	20	40	45	60	80	100	120	150	200	V						
Maximum Average Forward Rectified Current	I <sub>F(AV)</sub>	3.0									A						
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I <sub>FSM</sub>	80									A						
Max Instantaneous Forward Voltage at 3 A	V <sub>F</sub>	0.55		0.70		0.85		0.95			V						
Maximum DC Reverse Current T <sub>a</sub> = 25°C at Rated DC Reverse Voltage T <sub>a</sub> = 100°C	I <sub>R</sub>	0.5 5			0.3 3						mA						
Typical Junction Capacitance <sup>(1)</sup>	C <sub>j</sub>	450			400						pF						
Typical Thermal Resistance <sup>(2)</sup>	R <sub>θJA</sub>	70									°C/W						
Operating Junction Temperature Range	T <sub>j</sub>	-55 ~ +125									°C						
Storage Temperature Range	T <sub>stg</sub>	-55 ~ +150									°C						

( 1 ) Measured at 1 MHz and applied reverse voltage of 4 V D.C

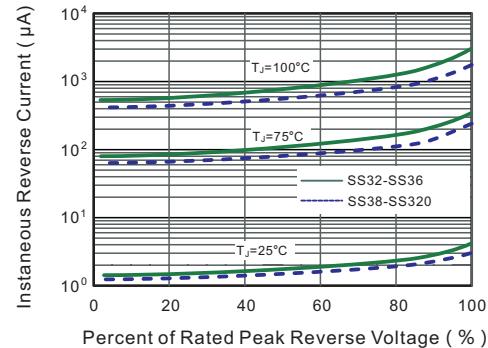
( 2 ) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

# SS32 THRU SS320

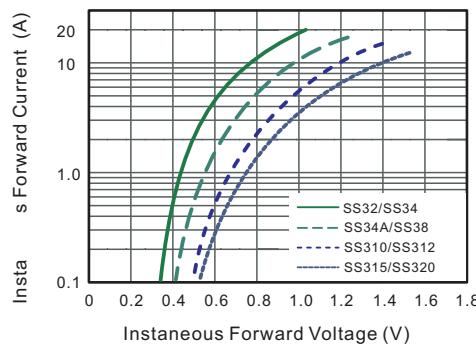
**Fig.1 Forward Current Derating Curve**



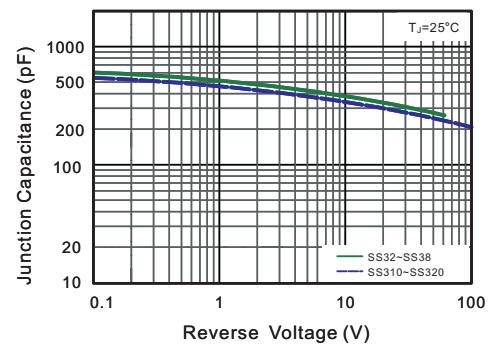
**Fig.2 Typical Reverse Characteristics**



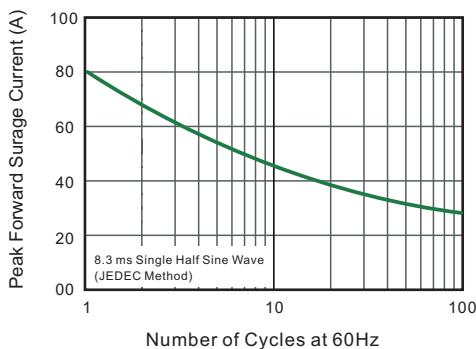
**Fig.3 Typical Forward Characteristic**



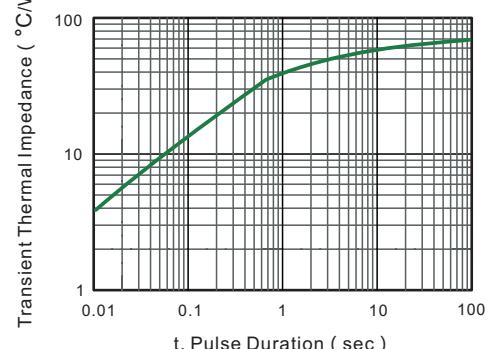
**Fig.4 Typical Junction Capacitance**



**Fig.5 Maximum Non-Repetitive Peak Forward Surge Current**



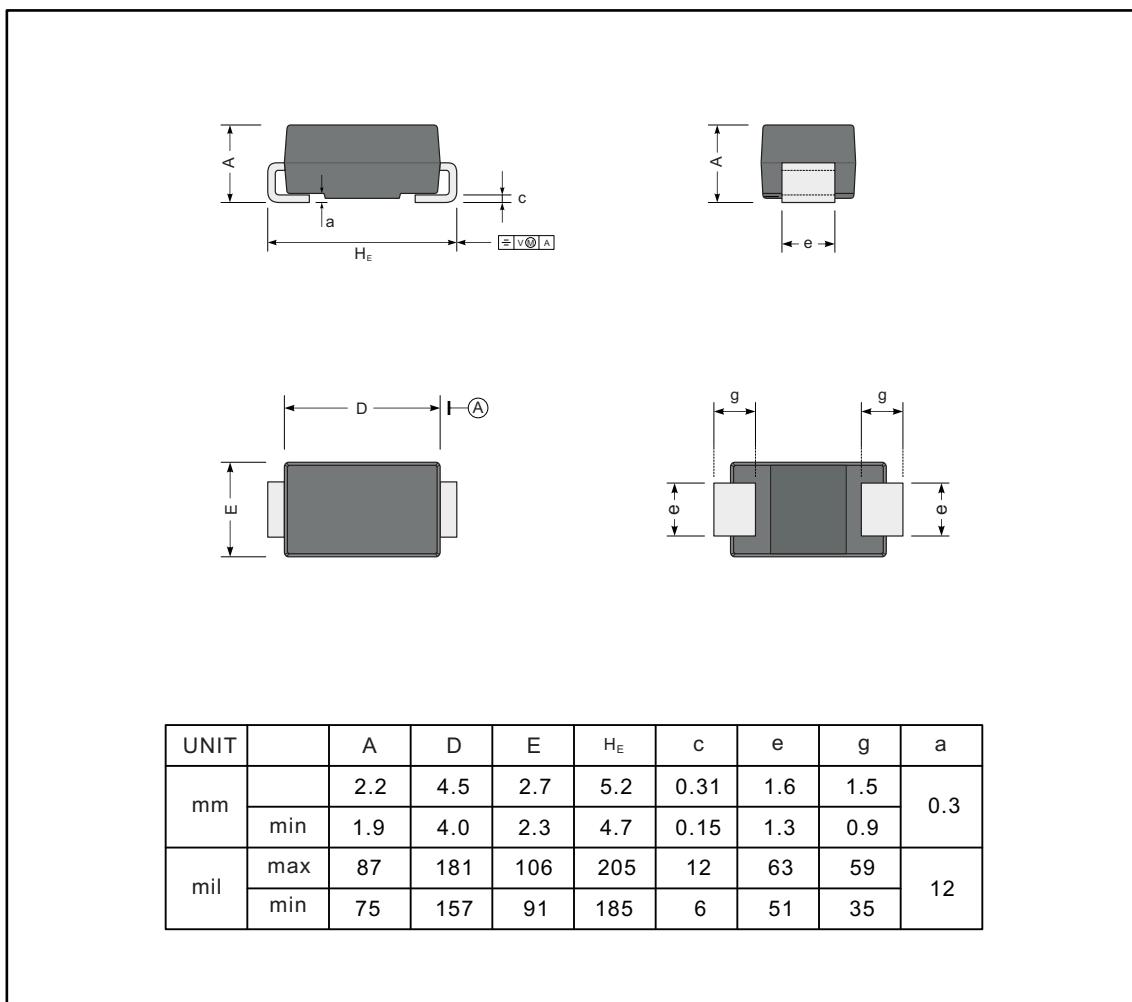
**Fig.5- Typical Transient Thermal Impedance**



## PACKAGE OUTLINE

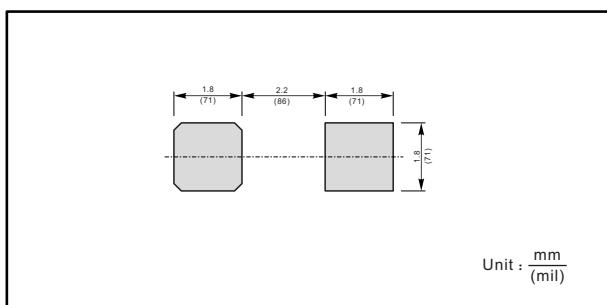
Plastic surface mounted package; 2 leads

SMA



UNIT		A	D	E	$H_E$	c	e	g	a
mm		2.2	4.5	2.7	5.2	0.31	1.6	1.5	0.3
	min	1.9	4.0	2.3	4.7	0.15	1.3	0.9	
mil	max	87	181	106	205	12	63	59	12
	min	75	157	91	185	6	51	35	

## The recommended mounting pad size



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